NSN 5961-01-379-0857

Unitized Semiconductor Devices - Page 1 of 1



View Online at https://aerobasegroup.com/nsn/5961-01-379-0857 **Inclosure Material:** Plastic **Overall Length:** Between 0.745 inches and 0.840 inches **Overall Height:** Between 0.260 inches and 0.345 inches Overall Width: 0.300 inches **Component Name And Quantity:** 5 transistor **Mounting Method:** Press fit **Semiconductor Material:** Silicon all transistor Voltage Rating In Volts Per Characteristic: 20.0 collector to base voltage/static/emitter open all transistor and 15.0 collector to emitter voltage/static/base open all transistor **Current Rating Per Characteristic:** 20.00 milliamperes source cutoff current all transistor **Power Rating Per Characteristic:** 425.0 milliwatts small-signal input power, common-collector absolute all transistor **Maximum Operating Tempurature Per Measurement Point:** 125.0 degrees celsius ambient air **Special Features:** All transistor junction pattern arrangement: npn **Terminal Type And Quantity:** 14 ferrule Shelf Life: N/a **Unit Of Measure: Demilitarization:** No Fiig: A110a0